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Inclosure Material:

Metal

Overall Length:

1.550 inches

Overall Height:

0.300 inches

Overall Width:

1.050 inches

End Application:

Tf2091b 09553

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact-darlington connected

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

60.0 collector to emitter voltage/static/base open and 60.0 collector to base voltage, dc and 5.0 emitter to base voltage, dc

Current Rating Per Characteristic:

4.00 amperes source cutoff current and 0.05 amperes source cutoff current

Power Rating Per Characteristic:

75.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

1 case and 2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

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